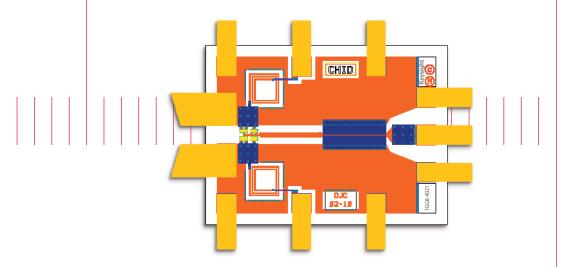
Keysight 1GG8-4021

V- and W-Band Waveguide Diode Mixer IC



Data Sheet

Features

- V-band conversion loss (x6 mixing):26 dB, typical
- W-band conversion loss (x8 mixing):29 dB, typical
- Beam-lead die



Description

The 1GG8-4021 is fabricated using the Keysight Technologies, Inc. Schottky diode process. It is a single-balanced mixer topology using anti-parallel diodes to enhance even-harmonic mixing. Typical use is in V-band and W-band waveguide mixers.

Absolute maximum ratings¹

| Parameter | Condition | Continu Min. | ous Use Max. | Damago Min. | e Level Max. | Units |
|---------------------------------|-------------------------|-----------------|-----------------|----------------|-----------------|-------|
| l _{diode} ² | RMS current, any diode | | 30 | | | mA |
| I _{peak} ² | Peak current, any diode | | 36 | | | mA |
| P _{total} ² | Total RF+LO CW power | | 22 | 25 | | dBm |
| T _A ² | Ambient temperature | | 65 | | | dBm |
| T _{st} | Storage temperature | -55 | 150 | | | °C |
| T _{max} ³ | Assembly temperature | -65 | 200 | | | °C |

- 1. Operation in excess of any of the values may result in permanent damage to the device.
- 2. MTTF >5 x 10⁵ hour. Operation in excess of T_A will degrade MTTF.
- 3. 60 second maximum

DC specifications¹

| Parameter | Condition | Min. | Тур. | Max. | Units |
|------------|----------------------|-------|------|-------|-------|
| VIFp_1mA | IFP to IFM at 1 mA | 1.28 | 1.48 | 1.68 | Volts |
| VIFp_n1mA | IFP to IFM at -1 mA | -1.68 | 1.48 | -1.28 | Volts |
| VIFp_10mA | IFP to IFM at 10 mA | 1.57 | 1.87 | 2.17 | Volts |
| VIFp_n10mA | IFP to IFM at -10 mA | -2.17 | 1.87 | -1.57 | Volts |

^{1.} T_A = 25 °C.

Frequency-domain RF specifications¹

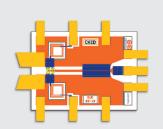
| Parameter | Condition | Min. | Тур. | Max. | Units |
|------------------------|-----------|------|------|------|-------|
| V-band conversion loss | ×6 mode | | 26 | | dB |
| W-band conversion loss | ×8 mode | | 29 | | dB |
| IF bandwidth | | 0 | | 1 | GHz |

^{1.} $T_A = 25$ °C, LO drive supplied by compressed AMMC-5024 amplifier, 4 V, 160 mA

ESD limits¹

| Parameter | Condition | Min. | Тур. | Max. | Units |
|-----------|----------------------|-------|------|-------|-------|
| IFP-IFM | IFP to IFM | -600 | | +600 | Volts |
| IF-GND | IFP or IFM to ground | -600 | | +600 | Volts |
| LO-GND | LO port to ground | -2200 | | +2200 | Volts |

^{1.} Human body model: 100 pF, $1.5 \text{ k}\Omega$.



- Chip Size: $970 \times 720 \ \mu m \pm 10 \ \mu m$ (38.2 x 28.3 mils $\pm 0.4 \ mils$)
- Chip Thickness: $58 \pm 15 \mu m (2.3 \pm 0.6 mils)$

Applications

The 1GG8-4021 is used in V- and W-band waveguide harmonic mixers.

Operation

The LO is applied single-ended to the LO port; an AMMC-5024 biased at 4 V and 160 mA, and run into compression has been found to be an effective LO drive (usually a directional detector will be placed between the LO amplifier and the 1GG8-4021 as well); harmonic content from the compressed LO amplifier enhances the mixer operation while keeping the diodes in a safe operating region. The RF from the waveguide is applied differentially to RFP and RFM; the IF emerges differentially from IFP and IFM, and is usually converted to a single-ended signal using an off-chip balun. The RF ports include an on-chip backshort optimized for V and W Band operation.

Biasing

The 1GG8-4021 is an unbiased mixer; proper LO drive is all that is required.

Assembly Techniques

The 1GG8-4021 is a beam lead device; the Keysight Technologies, Inc., *Beam Lead Diode Bonding and Handling Procedures - Application Note* (5991-3513EN) provides basic information.

GaAs MMICs are ESD sensitive. ESD preventive measures must be employed in all aspects of storage, handling and assembly. MMIC ESD precautions, handling considerations, and die attach and bonding methods are critical factors in successful GaAs MMIC performance and reliability.

Please refer to Keysight Technologies, Inc., GaAs MMIC ESD, Die Attach and Bonding Guidelines - Application Note (5991-3484EN) for additional information on these subjects.

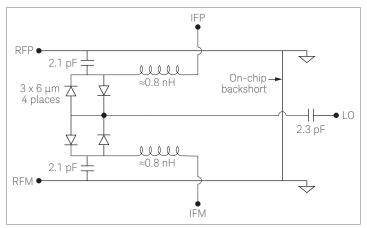


Figure 1. 1GG8-4021 electrical schematic

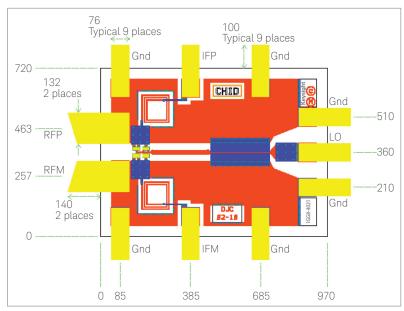


Figure 2. 1GG8-4021 beam-lead identification and location - all dimensions in microns

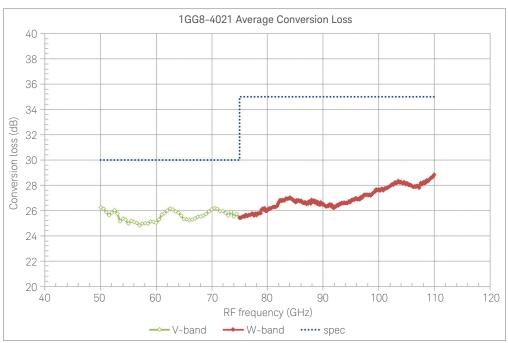
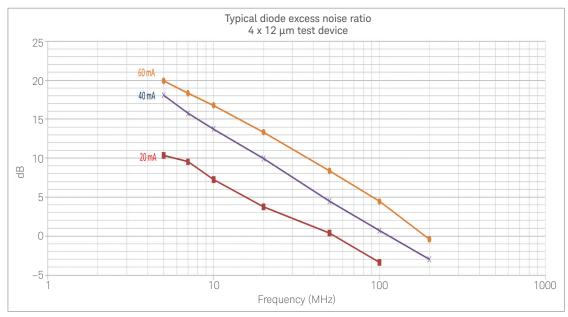


Figure 3. 1GG8-4021 operation in V- and W-band M1970 smart mixers

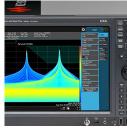


Figure~4.~1GG8-4021~typical~noise~of~a~forward-biased~sampler~diode.~The~1GG8-4021~contains~four~similarly~sized~diodes.

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The product described in this data sheet is RoHS Compliant. See RoHS Compliance section for more details.

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